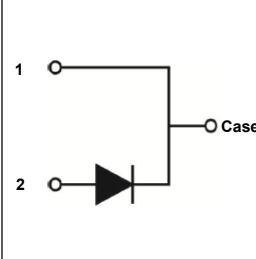


Fast Recovery Epitaxial Diode
●Features

- Planar Structure With EPI Wafer
- High Current Capability & Low Forward Voltage
- Low Switch Noise & High Sur Capability
- Low Power Loss & High Efficiency
- Guard Ring & Environmental Protection
- High Temperature Application
- Green Molding Compound(No Br,Sb)

●Application

- Half-Bridge/Full-Bridge Switched-Mode Power
- PC Power



$I_F(AV) : 60A$

$V_{RRM} : 1200V$

$T_{RR}(typ.): 85nS$



■ RoHS COMPLIANT

TO247-2

●Ordering Information:

Part Number	LHF60U120
Package	TO-247-2
Basic Ordering Unit (pcs)	330
Normal Package Material Ordering Code	LHF60U120T22-TO247-2-TU
Halogen Free Ordering Code	LHF60U120T22-TO247-2-TU-HF

●Maximum Ratings Characteristics ($T_A = 25^\circ C$ Unless otherwise Noted)

PARAMETER	SYMBOL	Value	UNIT
Repetitive Peak Reverse Voltage	V_{RRM}	1200	V
Working Peak Reverse Voltage	V_{RWM}	1200	V
DC blocking Voltage	V_{RM}	1200	V
Average Rectified Forward Current (Rated VR-20KHz Square Wave)-50% duty cycle	$I_{F(AV)}$	60	A
Non-Repetitive Peak Forward surge current (surge applied at rated load conditions half wave,single phase,60Hz)	I_{FSM}	360	A
Power Dissipation($T_C = 25^\circ C$)	P_{tot}	272	W
Maximum Rate of Voltage change(at rate VR)	dV/dt	10000	V/ μ S
Operating Temperature	T_J	-40~+175	$^\circ C$
Storage Temperature	T_{STG}	-40~+150	$^\circ C$

●Electronic Characteristics-(per leg)

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Forward Voltage Drop	VF	$I_F=60A, T_J=25^{\circ}C$	--	2.8	..	V
		$I_F=60A, T_J=125^{\circ}C$	--	2.4	3.5	
Reverse Current	IR	$V_R=V_{RRM}, T_J=25^{\circ}C$	--	--	5	uA
		$V_R=V_{RRM}, T_J=125^{\circ}C$	--	--	100	
Reverse Recovery Time	T_{RR}	$I_F=30A, V_R=30V, T_A=25^{\circ}C$	--	--	85	nS

●Thermal Characteristics

PARAMETER	SYMBOL	MAX	UNIT
Thermal Resistance Junction-case	R_{thJC}	2.0	$^{\circ}C/W$

● **Ratings and Characteristics Curves**

Fig. 1 Forward Current De-Rating Curve

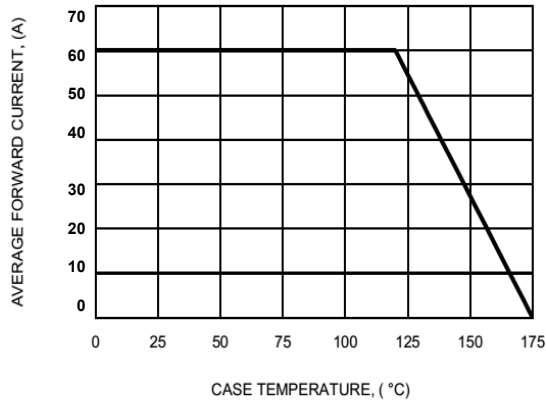


Fig. 2 Peak Forward Surge Current

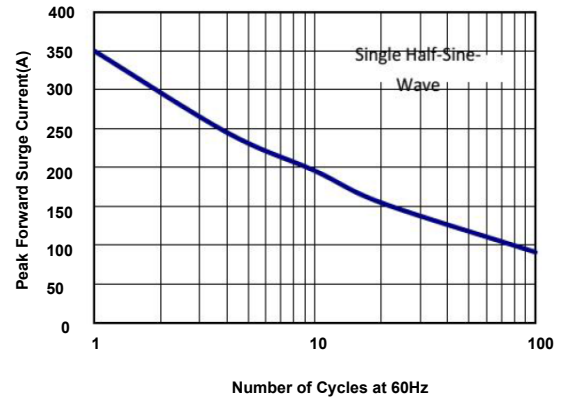


Fig. 3 Reverse Characteristics

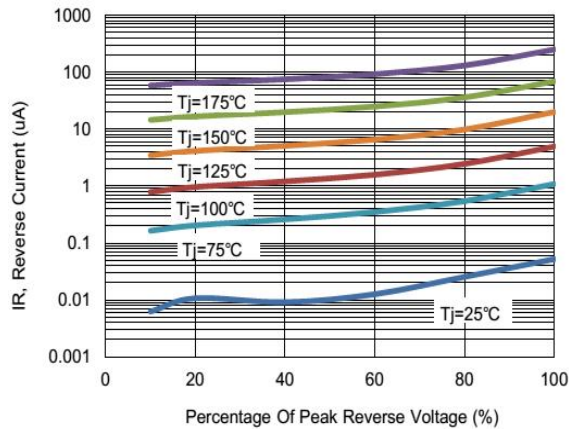


Fig. 4 Instantaneous Forward Characteristics

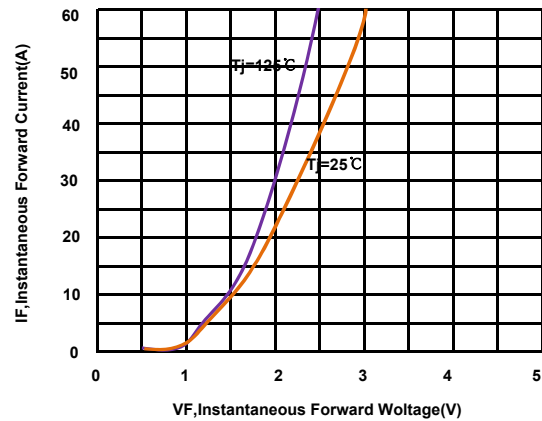
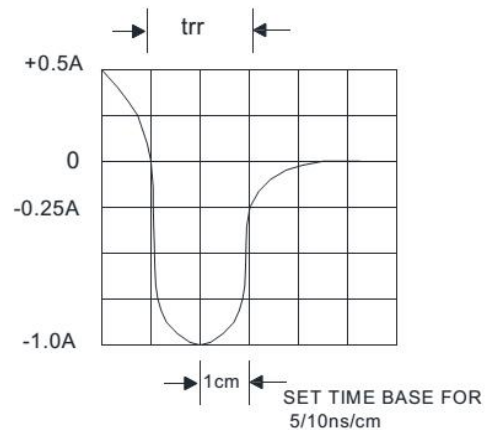
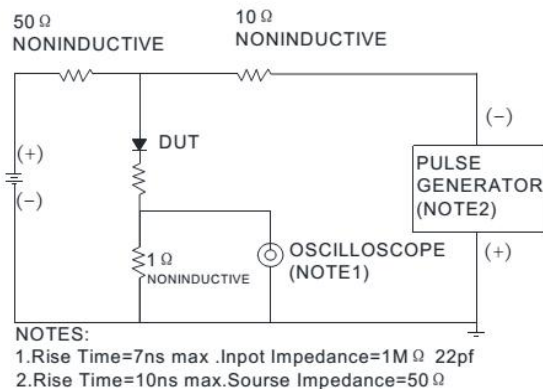


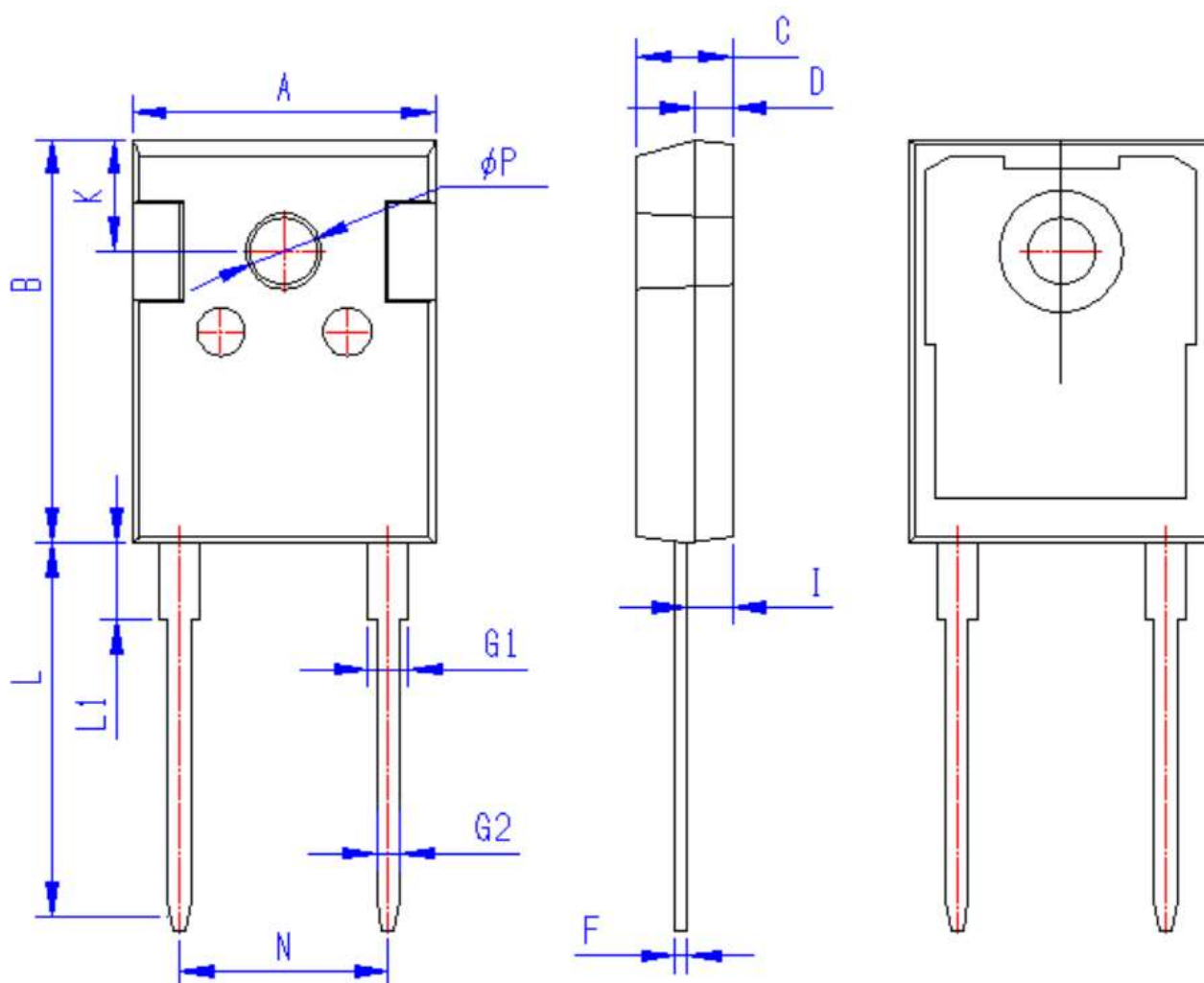
Fig. 5 Diagram of Circuit and Testing Wave Form of Reverse Recovery Time



•Dimensions (TO-247-2)

UNIT:mm

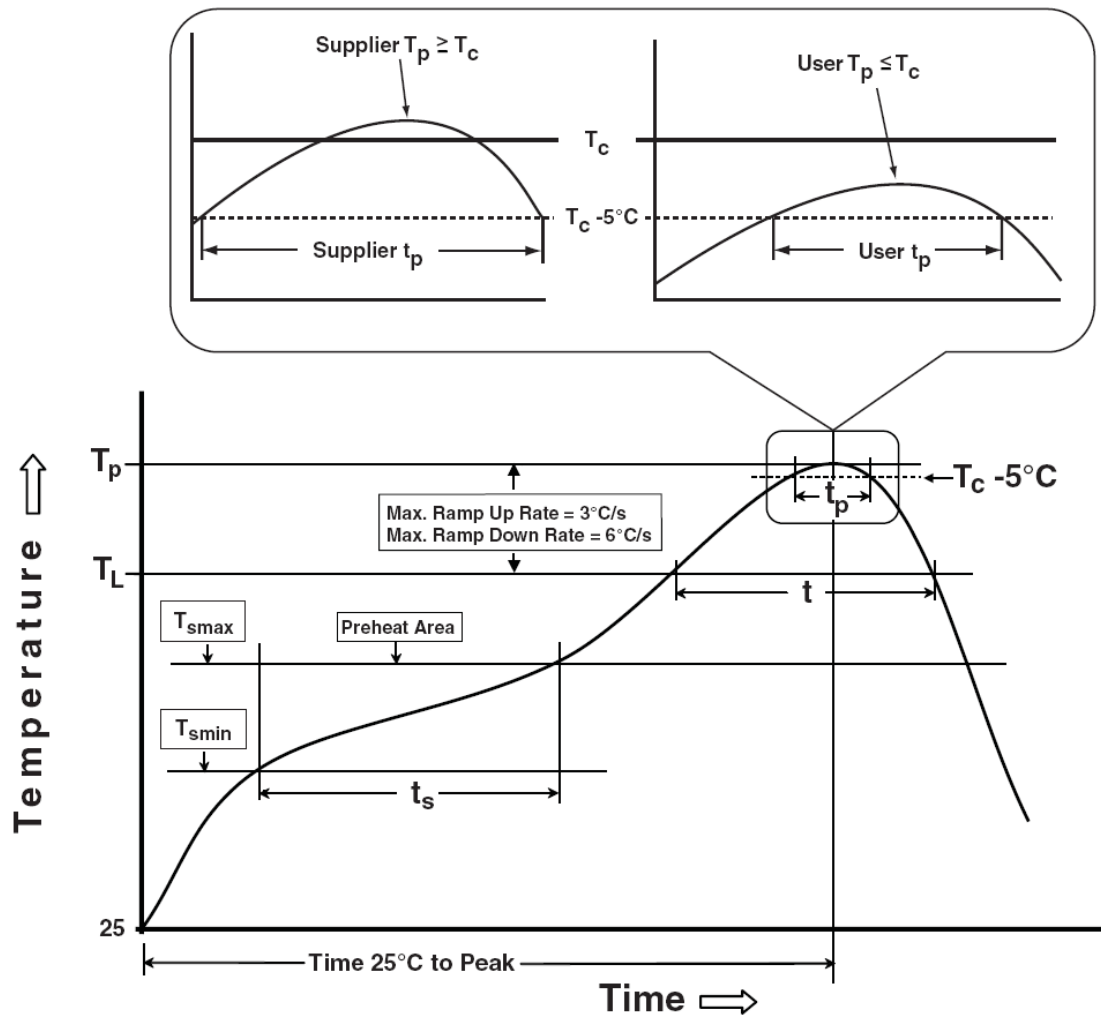
SYMBOL	Min	Max	SYMBOL	Min	Max
A	15.60	16.00	G2	1.15	1.25
B	20.80	21.20	N	5.25	5.65
C	4.80	5.20	L1	4.00	4.30
D	1.85	2.15	L	19.60	20.40
K	6.00	6.30	I	2.30	2.50
F	0.50	0.70	ΦP	3.30	3.70
G1	1.95	2.25			



• Mechanical

- Molder Plastic: UL Flammability Classification Rating 94V-0

• Classification Profile



• Classification Reflow Profiles

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Preheat & Soak Temperature min (T_{smin}) Temperature max (T_{smax}) Time (T_{smin} to T_{smax}) (t_s)	100 °C 150 °C 60-120 seconds	150 °C 200 °C 60-120 seconds
Average ramp-up rate (T_{smax} to T_p)	3 °C/second max.	3°C/second max.
Liquidous temperature (T_L) Time at liquidous (t_L)	183 °C 60-150 seconds	217 °C 60-150 seconds
Peak package body Temperature (T_p)*	See Classification Temp in table 1	See Classification Temp in table 2
Time (t_p)** within 5°C of the specified classification temperature (T_c)	20** seconds	30** seconds
Average ramp-down rate (T_p to T_{smax})	6 °C/second max.	6 °C/second max.
Time 25°C to peak temperature	6 minutes max.	8 minutes max.
* Tolerance for peak profile Temperature (T_p) is defined as a supplier minimum and a user maximum. ** Tolerance for time at peak profile temperature (t_p) is defined as a supplier minimum and a user maximum.		

Table 1. SnPb Eutectic Process – Classification Temperatures (T_c)

Package Thickness	Volume mm ³ <350	Volume mm ³ ≥350
<2.5 mm	235 °C	220 °C
≥2.5 mm	220 °C	220 °C

Table 2. Pb-free Process – Classification Temperatures (T_c)

Package Thickness	Volume mm ³ <350	Volume mm ³ 350-2000	Volume mm ³ >2000
<1.6 mm	260 °C	260 °C	260 °C
1.6 mm – 2.5 mm	260 °C	250 °C	245 °C
≥2.5 mm	250 °C	245 °C	245 °C

Reliability Test Program

Test item	Method	Description
SOLDERABILITY	JESD-22, B102	5 Sec, 245°C
HOLT	JESD-22, A108	1000 Hrs, Bias @ 125°C
PCT	JESD-22, A102	168 Hrs, 100%RH, 2atm, 121°C
TCT	JESD-22, A104	500 Cycles, -65°C~150°C